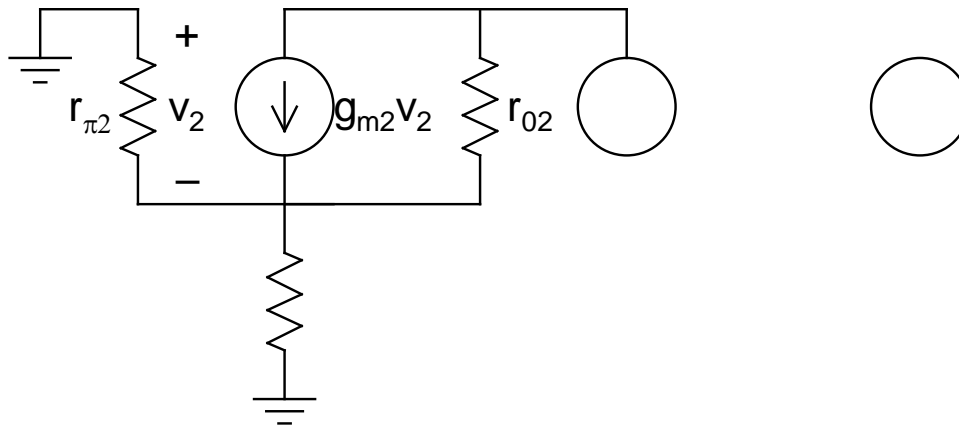


➤ *Calculation of  $R_o$ :*

- *Golden Rule can't be used since emitter of  $Q_2$  is not grounded ( $R_2$  present there)*
- *Needs analysis*
  - ⇒ *Leads to a module that is frequently encountered*
- *Base of  $Q_1$ - $Q_2$  at a fixed DC potential ⇒ **ac ground***



$$\begin{aligned}
 i_t &= g_{m2} v_2 + (v_t + v_2)/r_{02} \\
 &= v_t/r_{02} + (g_{m2} + 1/r_{02}) v_2 \quad v_t/r_{02} + g_{m2} v_2
 \end{aligned}$$

$$v_2 = -i_t R_{\text{eff}}$$

$$\Rightarrow i_t = v_t/r_{02} - g_{m2} R_{\text{eff}} i_t$$

$$\Rightarrow R_0 = v_t/i_t = r_{02}(1 + g_{m2} R_{\text{eff}})$$

➤ This is a ***Golden Equation***, which would be *used frequently*

- *Carefully note the topology that produces this result*

➤ ***Exercise***: *Reverse  $v_2$  and show that the expression for  $R_0$  remains invariant*

- If  $r_{\pi 2} \gg R_2$ ,  $R_0 = r_{02}(1 + g_{m2}R_2)$
- If  $R_2 \gg r_{\pi 2}$ ,  $R_0 \approx \beta_2 r_{02}$  (since  $\beta = g_m r_{\pi} \gg 1$ )
- *Under the second condition, the circuit produces enormously large value of  $R_0 \sim 10s$  of  $M\Omega$  or greater*
  - *Almost approaches a constant current source!*
- *It's good to check the relative values of  $R_2$  and  $r_{\pi 2}$  before using either of the equations*
- *This circuit does not have any MOS counterpart for obvious reasons!*

- *Cascode Current Source:*
  - *The best and most widely used*
  - *Almost universal choice for biasing IC stages*
  - *Produces extremely high  $R_o$*
  - *Original cascode needs higher values of  $V_{0,min}$*
  - *Modified cascode gets rid of this problem and pushes  $V_{0,min}$  down*
  - *The topology is basically two simple CMs stacked one upon the other*
  - *Both npn and NMOS implementations exist*

- *nnp Cascode:*

- *All  $Q_s$  are perfectly matched*

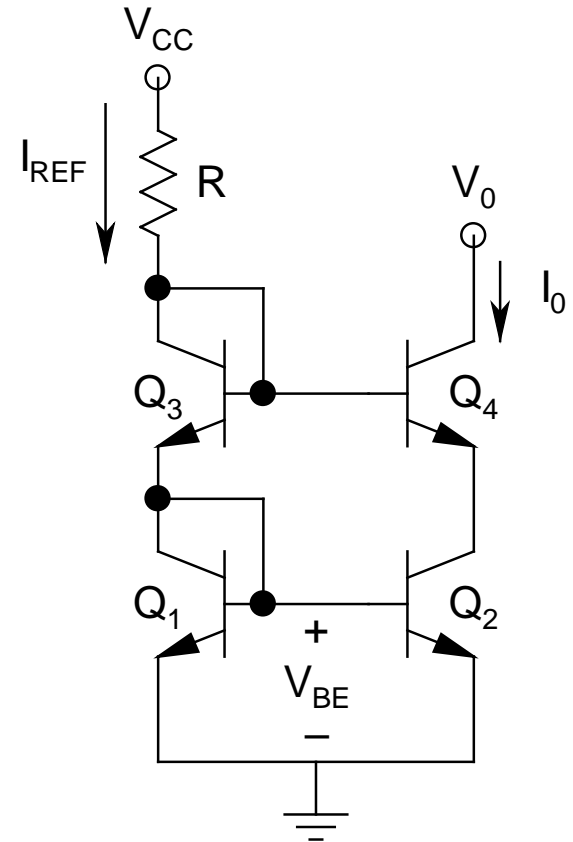
- *Neglecting  $I_B$  and  $V_A$ :*

$$I_0 = I_{REF} = (V_{CC} - 2V_{BE})/R$$

- Show that if  *$I_B$  can't be neglected*, but *all  $Q_s$  have same  $\beta$* :

$$I_0 = \frac{I_{REF}}{1 + (4\beta + 2)/\beta^2}$$

- Thus,  *$\beta$  immunity is not that pronounced*



➤ *All  $Q$ s operate with the same  $V_{BE}$*

$$\Rightarrow V_{B1} = V_{B2} = V_{BE}, V_{B3} = V_{B4} = 2V_{BE}$$

$$\Rightarrow V_{E4} = V_{C2} = V_{BE}$$

$$\Rightarrow V_{BE2} = V_{CE2}$$

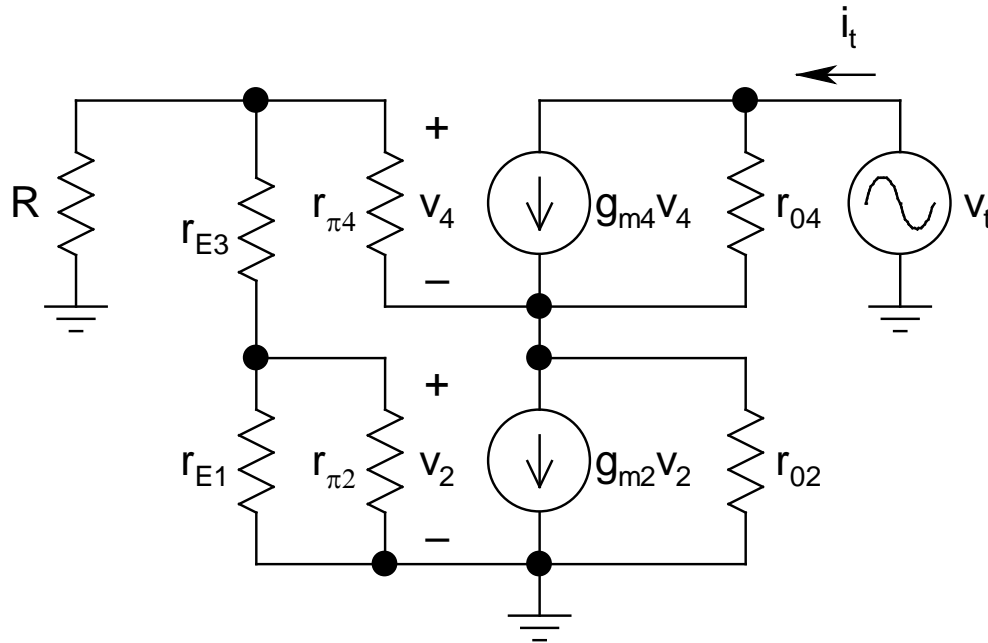
$\Rightarrow$   *$Q_2$  can never saturate, but  $Q_4$  can!*

$$\Rightarrow V_{0,\min} = V_{BE} + V_{CE4}(\text{SS}) = 0.7 + 0.2 = 0.9 \text{ V}$$

➤ *The output voltage swing is sacrificed quite a bit!*

➤ *However, the main advantage of this circuit is enormously large  $R_0$*

➤ *Calculation of  $R_o$ :*



- *$Q_1$  and  $Q_3$  diode-connected  $\Rightarrow r_{E1}$  and  $r_{E3}$*

- Note that to a *first-order estimate*, *bases of  $Q_1$ - $Q_2$  and  $Q_3$ - $Q_4$*  can be considered to be at a *fixed DC potential*, and thus, *ac ground*

$$\Rightarrow v_2 = 0 \Rightarrow g_{m2}v_2 = 0$$

$\Rightarrow$  Leads to the *simplified equivalent* (looks familiar?)

- *By inspection:*

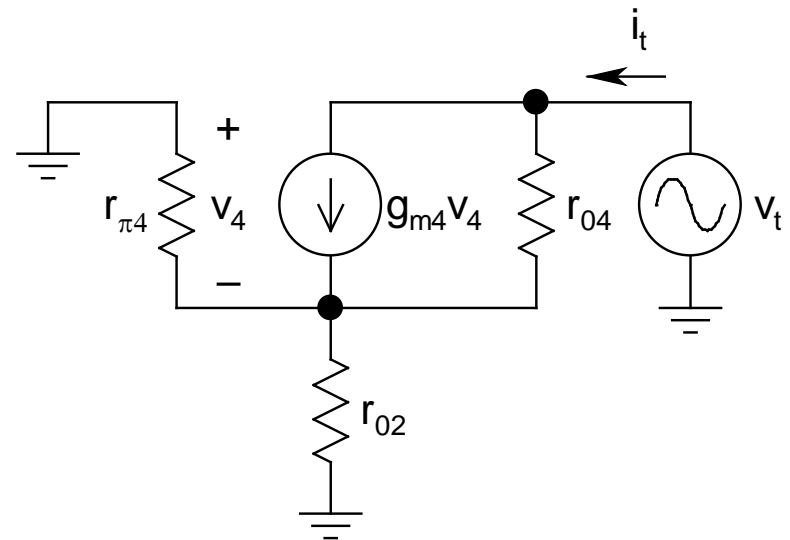
$$R_0 \approx r_{o4}(1 + g_{m4}r_{\pi4})$$

$$\approx \beta_4 r_{o4}$$

(*assuming  $r_{o2} \gg r_{\pi4}$* )

- *Actual analysis gives:*

$$R_0 = \beta_4 r_{o4}/2 \text{ (large error!)}$$





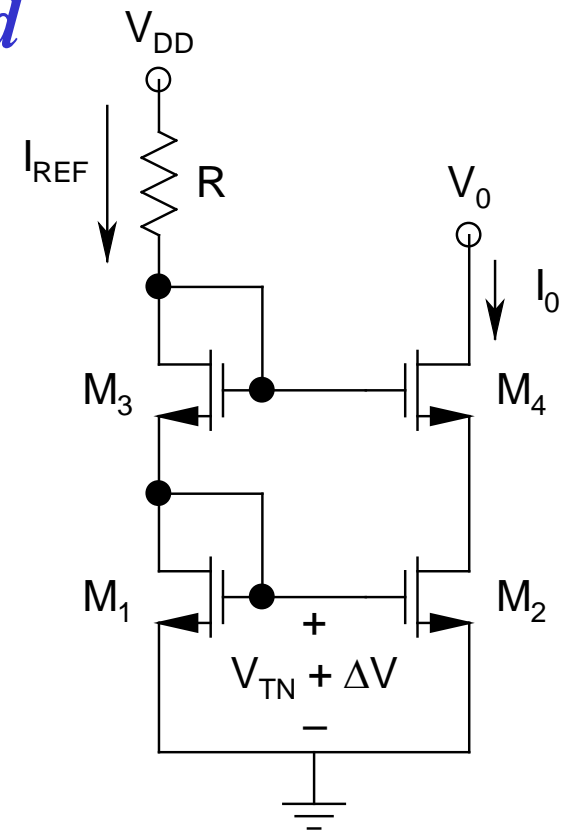
- ***NMOS Cascode:***

- *All  $M$ s perfectly matched*
- *All bodies connected to ground*

- *$M_1$ - $M_2$  does not have body effect, but  $M_3$ - $M_4$  does!*
- *Makes hand analysis quite tedious*

⇒ *Neglect body effect*

- *All  $M$ s operate with same  $V_{GS}$*
- Define  $\Delta V = V_{GS} - V_{TN} = V_{GT}$ 
  - $\Delta V =$  *Gate Overdrive*



➤ *The reference current:*

$$I_{\text{REF}} = \frac{V_{\text{DD}} - 2V_{\text{GS}}}{R} = \frac{k_{\text{N}}}{2} V_{\text{GT}}^2 \quad (\text{neglecting } \lambda)$$

➤  *$V_{\text{GS}}$  and  $I_{\text{REF}}$  can be found  $\Rightarrow I_0 = I_{\text{REF}}$*

➤  $V_{\text{G1}} = V_{\text{G2}} = V_{\text{GS}} = V_{\text{TN}} + \Delta V$

➤  $V_{\text{G3}} = V_{\text{G4}} = 2V_{\text{GS}} = 2(V_{\text{TN}} + \Delta V)$

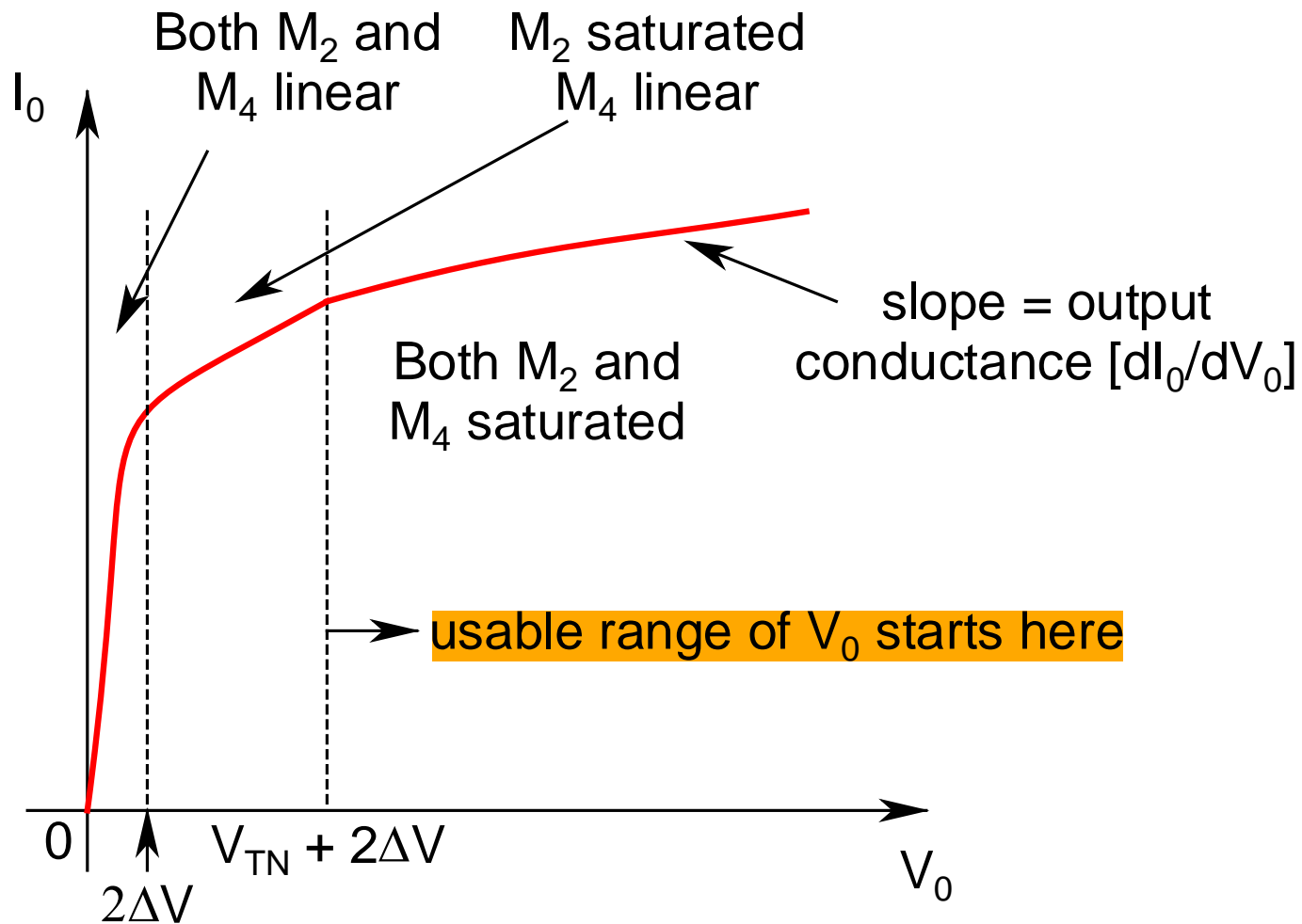
➤  $V_{\text{S4}} = V_{\text{D2}} = V_{\text{TN}} + \Delta V$

$$\Rightarrow V_{\text{GS2}} = V_{\text{DS2}}$$

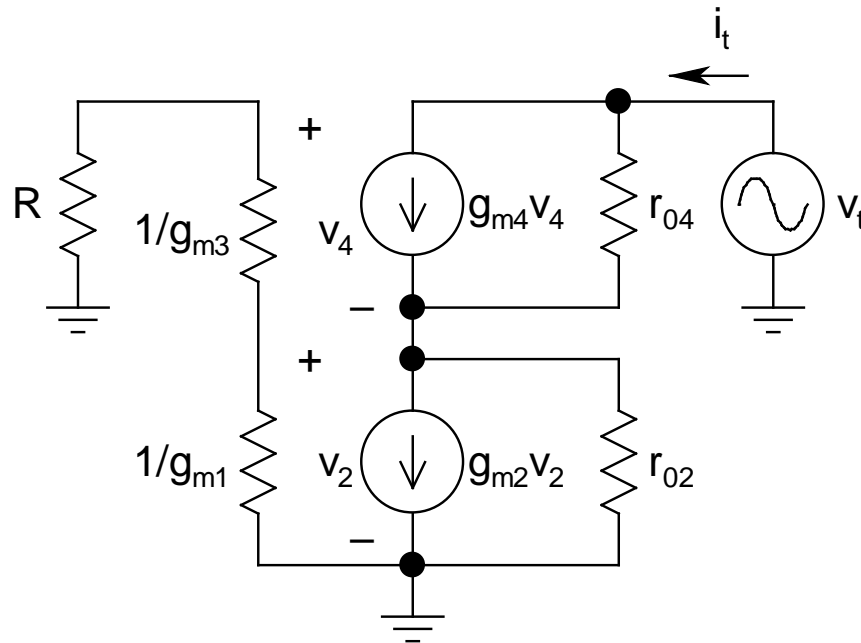
$\Rightarrow$   *$M_2$  can never enter linear region*

$$\Rightarrow V_{0,\text{min}} = V_{\text{DS2}} + V_{\text{DS4}} = V_{\text{TN}} + 2\Delta V$$

- *This can be quite significant, since  $V_{TN}$  is added to  $\Delta V$* 
  - *Assuming  $\Delta V \sim 0.1$  V and  $V_{TN} \sim 0.7$  V,  $V_{0,min} \sim 0.9$  V, which is very large*
  - *This is one of the drawbacks of this simple cascode circuit (modified cascode doesn't have this problem)*
- *If  $V_0$  drops below  $(V_{TN} + 2\Delta V)$ , first  $M_4$  enters linear region, and circuit performance starts to get affected*
- *For further drop in  $V_0$ ,  $M_2$  also enters linear region, and the current mirror collapses!*



➤ *Calculation of  $R_o$ :*



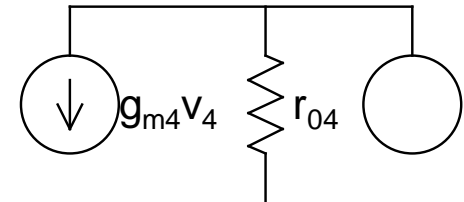
Exact Equivalent

- *$M_1$  and  $M_3$  diode-connected*  $\Rightarrow 1/g_{m1}$  and  $1/g_{m3}$

- *The left part of the circuit has no source*

$$\Rightarrow v_2 = 0 \Rightarrow g_{m2}v_2 = 0$$

$\Rightarrow$  *Leads to the simplified equivalent* (now should look very familiar!)



- *By inspection:*

$$R_0 \approx r_{o4}(1 + g_{m4}r_{o2})$$

$$\approx g_{m4}r_{o2}r_{o4}$$

- *Can be huge!*